Ų	'n
٠,	んりつ

Notice of Allowability 09/895,579	Application No.	Applicant(s)	
	09/895,579	DOYLE ET AL.	
Notice of Anowability	Examiner	DOYLE ET AL. Art Unit 2818 Ver sheet with the correspondence address) CLOSED in this application. If not included oriate communication will be mailed in due co oplication is subject to withdrawal from issue at 08. 119(a)-(d) or (f). in Application No in Application No seen received in this national stage application \$ 119(e) (to a provisional application). seen received. \$\$ 120 and/or 121. ation to file a reply complying with the require THIS THREE-MONTH PERIOD IS NOT EX- attached EXAMINER'S AMENDMENT or NO.	
	David Nhu	2818	
The MAILING DATE of this communication appeal claims being allowable, PROSECUTION ON THE MERITS IS herewith (or previously mailed), a Notice of Allowance (PTOL-85) NOTICE OF ALLOWABILITY IS NOT A GRANT OF PATENT RIOF the Office or upon petition by the applicant. See 37 CFR 1.313	(OR REMAINS) CLOSED in or other appropriate commem GHTS. This application is	n this application. If not included unication will be mailed in due of	l ourse. THIS
2. X The allowed claim(s) is/are <u>14, 16-18, 20-27</u> .			
 3. The drawings filed on 29 June 2001 are accepted by the E 4. Acknowledgment is made of a claim for foreign priority und a) All b) Some* c) None of the: 		or (f).	
1. Certified copies of the priority documents have	been received.		
2. Certified copies of the priority documents have	been received in Application	on No	
3. ☐ Copies of the certified copies of the priority doc International Bureau (PCT Rule 17.2(a)).	cuments have been receive	d in this national stage application	on from the
* Certified copies not received: 5. Acknowledgment is made of a claim for domestic priority ur			
(a) The translation of the foreign language provisional a	• •		
6. Acknowledgment is made of a claim for domestic priority ur	ider 35 U.S.C. 99 120 and/	or 121.	
Applicant has THREE MONTHS FROM THE "MAILING DATE" of below. Failure to timely comply will result in ABANDONMENT of t	this communication to file a his application. THIS THE	a reply complying with the requir REE-MONTH PERIOD IS NOT E	ements noted XTENDABLE.
7. A SUBSTITUTE OATH OR DECLARATION must be subm INFORMAL PATENT APPLICATION (PTO-152) which gives reas	itted. Note the attached EX on(s) why the oath or decla	AMINER'S AMENDMENT or NO ration is deficient.	TICE OF
8. ☐ CORRECTED DRAWINGS must be submitted. (a) ☐ including changes required by the Notice of Draftspers 1) ☐ hereto or 2) ☐ to Paper No		,	
(b) ☐ including changes required by the proposed drawing c		, , ,	
(c) including changes required by the attached Examiner	s Amendment / Comment o	or in the Office action of Paper N	o
Identifying indicia such as the application number (see 37 CFR 1. each sheet.	84(c)) should be written on t	he drawings in the front (not the b	ack) of
9. DEPOSIT OF and/or INFORMATION about the depos attached Examiner's comment regarding REQUIREMENT FOR The			te the
Attachm nt(s)			
 Notice of References Cited (PTO-892) Notice of Draftperson's Patent Drawing Review (PTO-948) Information Disclosure Statements (PTO-1449), Paper No	4∏ Interviev 6∏ Examin	of Informal Patent Application (P w Summary (PTO-413), Paper N er's Amendment/Comment er's Statement of Reasons for Al	0
		Amora	

Application/Control Number: 09/895,579

Art Unit: 2818

REASONS FOR ALLOWANCE

1. Claims 14, 16-18, 20-27 are allowed.

2. The following is an examiner's statement of reasons for allowance: None of the references of record teaches or suggests as cited in claims 14, 17: a relaxed layer comprising an embrittled region; a strained silicon layer in contact with the relaxed layer, the strained silicon layer to be transferred to top of a wafer by a heat treatment, the wafer having a base substrate and an oxidized (as cited in claim 14); a strained silicon layer on top of the SiO2 (silicon oxide/dioxide) layer, the strained silicon layer being transferred from a wafer, the wafer having an embrittled region and a stack structure of a base substrate and a layer of relaxed film (as cited in claim 17).

3. Any comments considered necessary by applicant must be submitted no later than the payment of the issue fee and, to avoid processing delays, should preferably accompany the issue fee. Such submissions should be clearly labeled "Comments on Statement of Reasons for Allowance."

CONCLUSION

- 4. The prior art made of record and not relied upon is considered pertinent to applicant's disclosure: Liaw et al (5,891,769): Method for Forming a Semiconductor Device Having a Heteroepitaxial Layer.
- 5. Any inquiry concerning this communication on earlier communications from the examiner should be directed to David Nhu, (703) 306-5796. The examiner can normally be reached on Monday-Friday from 7:30 AM to 5:00 PM.

The examiner's supervisor, David Nelms can be reached on (703) 308-4910.

Page 2

Application/Control Number: 09/895,579

Art Unit: 2818

The fax phone number for the organization where this application or proceeding is assigned is (703) 308-7382.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is (703) 308-0956

David Nhu

لمع

October 17, 2003

P.E. Dard Ven

Page 3